CEPC SDT on CEPCSW Status



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CEPC Tracker Meeting

Introduction

- Three existing detector concept for CDR
 - Silicon + TPC
 - Full Silicon Tracker
 - IDEA Concept







- The 4th detector concept
 - Silicon Vertex + Siliconn Tracker for momentum measurement
 - Drift chamber optimized for PID
 - Transverse crystal bar ECAL optimized for π^0/γ reconstruction
 - Solenoid magnet between HCAL and ECAL



Studies based on LDT software

Configuration for simulation study from Yangzhou meeting (v0)





Sub detector	N layers	Resolustion (µm)		Material budget (%X ₀)
		r-ф	Z	
VXD	6	2.8/6/4/4/4/4	2.8/6/4/4/4/4	0.15 per layer
SIT	4	7.2	86.6	0.65 per layer
DC (cell 1x1cm ²)	100	100	2000	1.2
SET	1	7.2	86.6	0.65
Total	111			5.35

New config for Silicon + Drift chamber: 4 layers of silicon (v1)



shows better resolution at this momentum range

Switching to CEPCSW

Current status from the CEPCSW (Drift chamber)

- Detector configuration: vertex + silicon + 2*drift chamber
- Fitting programme (Genfit2) with driftchamber+silicon detectors
- Outcome: could produce the momentum resolution





Momentum resolution

500event @ 100GeV

different configuration (from the one shown in the Yangzhou meeting)
number of events
further verifications



Plan for CEPCSW

- Prepare the detector config file for v1 (i.e. 4 layers of Si + 1 DCH)
- Obtain the momentum resolution figure (with the help from CEPCSW developers)
- Focus on the barrel region
 - Material buget dependent from DCH (which side)
 - Momentum reso. w/ and w/o DCH
 - Parameters of DCH (thickness, cell size, gas)
 - Other angles in barrel
 - PID performance